NSN 5961-00-439-3784

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-439-3784 **Inclosure Material:** Glass **Overall Length:** 1.220 inches **Terminal Length:** 1.640 inches **Overall Diameter:** 0.641 inches **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 120.0 breakdown voltage, dc **Current Rating Per Characteristic:** 7.00 milliamperes repetitive peak forward current **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization:

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